## NSN 5962-01-445-3269

Memory Microcircuit - Page 1 of 1



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| Operating Tempurature Range:  |
|---|
| -55.0/+125.0 degrees celsius  |
| Storage Tempurature Range:  |
| -65.0/+150.0 degrees celsius  |
| End Application:  |
| F-15i   |
| Features Provided:  |
| Electrostatic sensitive and monolithic and programmable and tested to mil-std-883 |
| Inclosure Material:   |
| Ceramic   |
| Inclosure Configuration:  |
| Dual-in-line  |
| Output Logic Form:  |
| Complementary-metal oxide-semiconductor logic                                     |
| Input Circuit Pattern:  |
| 22 input  |
| Criticality Code Justification:   |
| Cbbl and feat   |
| Product Name:   |
| Firmware, microcircuit, digital-programmable logic                                |
| Voltage Rating And Type Per Characteristic:                                       |
| -0.5 volts total supply and 7.0 volts total supply                                |
| Memory Device Type:   |
| Pal   |
| Special Features:   |
| Altered item made from 5962-8984106lx   |
| Terminal Type And Quantity:   |
| 24 pin  |
| Shelf Life:   |
| N/a   |
| Unit Of Measure:  |
| <del>-</del>  |
| Demilitarization:   |
| No  |
| Fiig:   |
| A458a0  |
|   |
|   |